NSN 5961-01-319-2504

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-319-2504 **Inclosure Material:** Plastic **Overall Length:** 0.845 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.482 inches **Overall Width:** 0.500 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-218 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 450.0 breakdown voltage, collector-to-emitter, base open and 1000.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter **Current Rating Per Characteristic:** 8.00 amperes source cutoff current and 1.00 milliamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 125.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 6.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 140.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**